

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[IXYS Corporation](#)
[MII300-12E4](#)

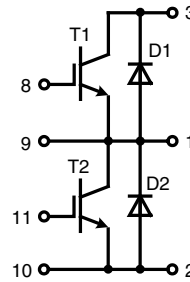
For any questions, you can email us directly:
sales@integrated-circuit.com

IXYS **MII 300-12 E4**

IGBT Module
phaseleg

$I_{C25} = 280 \text{ A}$
 $V_{CES} = 1200 \text{ V}$
 $V_{CE(sat) \text{ typ.}} = 2.2 \text{ V}$

Preliminary data



IGBTs T1 - T2

Symbol	Conditions	Maximum Ratings	
V_{CES}	$T_{VJ} = 25^{\circ}\text{C to } 125^{\circ}\text{C}$	1200	V
V_{GES}		± 20	V
I_{C25}	$T_C = 25^{\circ}\text{C}$	280	A
I_{C80}	$T_C = 80^{\circ}\text{C}$	200	A
I_{CM}	$V_{GE} = \pm 15 \text{ V}; R_G = 7.5 \Omega; T_{VJ} = 125^{\circ}\text{C}$	300	A
V_{CEK}	RBSOA Clamped inductive load; $L = 100 \mu\text{H}$	V_{CES}	
t_{SC} (SCSOA)	$V_{CE} = 900 \text{ V}; V_{GE} = \pm 15 \text{ V}; R_G = 7.5 \Omega$ $T_{VJ} = 125^{\circ}\text{C}; \text{non-repetitive}$	10	μs
P_{tot}	$T_C = 25^{\circ}\text{C}$	1100	W

Features

- NPT³ IGBT
 - low saturation voltage
 - positive temperature coefficient
 - fast switching
 - short tail current for optimized performance in resonant circuits
- HiPerFREDTM diodes
 - fast and soft reverse recovery
 - low operating forward voltage
 - low leakage current
- Package
 - low inductive current path
 - screw connection to high current main terminals
 - use of non interchangeable connectors for auxiliary terminals possible
 - kelvin emitter terminal for easy drive
 - isolated ceramic base plate

Symbol Conditions Characteristic Values
($T_{VJ} = 25^{\circ}\text{C}$, unless otherwise specified)

Symbol	Conditions	min.	typ.	max.		
$V_{CE(sat)}$	$I_C = 200 \text{ A}; V_{GE} = 15 \text{ V};$ $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		2.2 2.6	2.8	V V	
$V_{GE(th)}$	$I_C = 6 \text{ mA}; V_{GE} = V_{CE}$	4.5	5.5	6.5	V	
I_{CES}	$V_{CE} = V_{CES}; V_{GE} = 0 \text{ V};$ $T_{VJ} = 25^{\circ}\text{C}$ $T_{VJ} = 125^{\circ}\text{C}$		0.8 3.5	3.3	mA mA	
I_{GES}	$V_{CE} = 0 \text{ V}; V_{GE} = \pm 20 \text{ V}$			400	nA	
$t_{d(on)}$ t_r $t_{d(off)}$ t_f E_{on} E_{off}	Inductive load, $T_{VJ} = 125^{\circ}\text{C}$ $V_{CE} = 600 \text{ V}; I_C = 200 \text{ A}$ $V_{GE} = \pm 15 \text{ V}; R_G = 7.5 \Omega$		170 60 680 50 29 20		ns ns ns ns mJ mJ	
C_{ies}		$V_{CE} = 25 \text{ V}; V_{GE} = 0 \text{ V}; f = 1 \text{ MHz}$		11		nF
Q_{Gon}		$V_{CE} = 600 \text{ V}; V_{GE} = 15 \text{ V}; I_C = 200 \text{ A}$		1.16		μC
R_{thJC} R_{thJH}		(per IGBT) with heatsink compound		0.22	0.11	K/W K/W

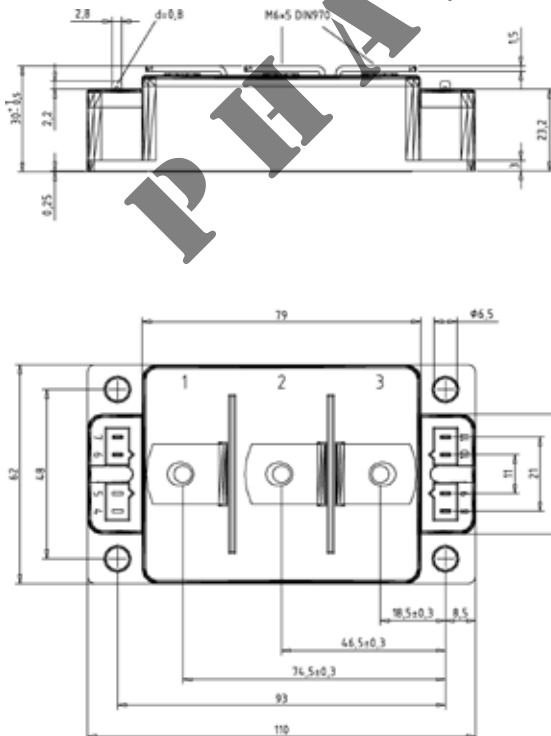
Applications

- drives
 - AC
 - DC
- power supplies
 - rectifiers with power factor correction and recuperation capability
 - UPS

Free wheeling diodes D1 - D2					
Symbol	Conditions	Maximum Ratings			
I_{F25}	$T_C = 25^\circ\text{C}$	300	A		
I_{F80}	$T_C = 80^\circ\text{C}$	190	A		
Symbol	Conditions	Characteristic Values			
		min.	typ.	max.	
V_F	$I_F = 200\text{ A}; V_{GE} = 0\text{ V};$	$T_{VJ} = 25^\circ\text{C}$	2.3	2.7	V
		$T_{VJ} = 125^\circ\text{C}$	1.7		V
I_{RM} t_{rr}	$I_F = 150\text{ A}; di_F/dt = 1500\text{ A}/\mu\text{s};$ $V_R = 600\text{ V}; V_{GE} = 0\text{ V};$	$T_{VJ} = 125^\circ\text{C}$	160		A
			220		ns
R_{thJC} R_{thJH}	(per IGBT) with heatsink compound	0.45	0.23		K/W K/W

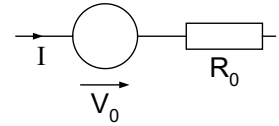
Module					
Symbol	Conditions	Maximum Ratings			
T_{VJ}	operating	-40...+150	$^\circ\text{C}$		
T_{stg}		-40...+125	$^\circ\text{C}$		
V_{ISO}	$I_{ISOL} \leq 1\text{ mA}; 50/60\text{ Hz}$	4000	V~		
M_d	Mounting torque (module, M6) (terminal, M6)	2.25 - 2.75	Nm		
		4.5 - 5.5	Nm		
Symbol	Conditions	Characteristic Values			
		min.	typ.	max.	
d_s	Creepage distance on surface	2			mm
d_A	Strike distance in air	2			mm
Weight		250			g

Dimensions in mm (1 mm = 0.0394")



Equivalent Circuits for Simulation

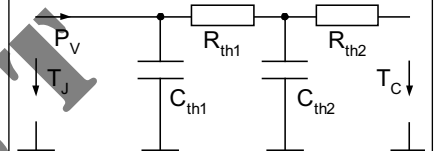
Conduction



IGBT (typ. at $V_{GE} = 15\text{ V}; T_J = 125^\circ\text{C}$)
 $V_0 = 1.0\text{ V}; R_0 = 8\text{ m}\Omega$

Free Wheeling Diode D1-D2 (typ. at $T_J = 125^\circ\text{C}$)
 $V_0 = 1.3\text{ V}; R_0 = 2\text{ m}\Omega$

Thermal Response



IGBT (typ.)
 $C_{th1} = tbd\text{ J/K}; R_{th1} = tbd\text{ K/W}$
 $C_{th2} = tbd\text{ J/K}; R_{th2} = tbd\text{ K/W}$

Free Wheeling Diode D1-D2 (typ.)
 $C_{th1} = tbd\text{ J/K}; R_{th1} = tbd\text{ K/W}$
 $C_{th2} = tbd\text{ J/K}; R_{th2} = tbd\text{ K/W}$

Optional accessories for modules

keyed twin plugs
 (UL758, style 1385, CSA class 5851, guide 460-1-1)

- Type ZY180L with wire length 350mm
 – for pins 4 (yellow wire) and 5 (red wire)
 – for pins 11 (yellow wire) and 10 (red wire)
- Type ZY180R with wire length 350mm
 – for pins 7 (yellow wire) and 6 (red wire)
 – for pins 8 (yellow wire) and 9 (red wire)